

Notice of References Cited	Application/Control No. 10/763,588		Applicant(s)/Patent Under Reexamination GEHRKE ET AL.	
	Examiner Maria Guerrero		Art Unit 2822	Page 1 of 1

U.S. PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	A	US-6,376,339 B2	04-2002	Linthicum et al.	438/479
*	B	US-6,261,929 B1	07-2001	Gehrke et al.	438/478
*	C	US-5,795,798	08-1998	Mishra et al.	438/35
*	D	US-5,880,485 A	03-1999	Marx et al.	257/94
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	I	US-			
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	K	US-			
	L	US-			
	M	US-			

FOREIGN PATENT DOCUMENTS

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Country	Name	Classification
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NON-PATENT DOCUMENTS

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Murakami et al., "Growth of Si-doped ALGAN on (0001) sapphire substrate by metalorganic vapor phase epitaxy", Journal of Crystal Growth 115, 1991, pages 648-651.
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*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.